



Technical Data Sheet

5mm Silicon Phototransistor T-1 3/4

PT534-6B

Features

- Fast response time
- High photo sensitivity
- Pb free

Descriptions

- PT534-6B is a high speed and high sensitive NPN silicon phototransistor molded in a standard $\phi 5$ mm package. Due to its black epoxy the device is sensitive to visible and near infrared radiation..



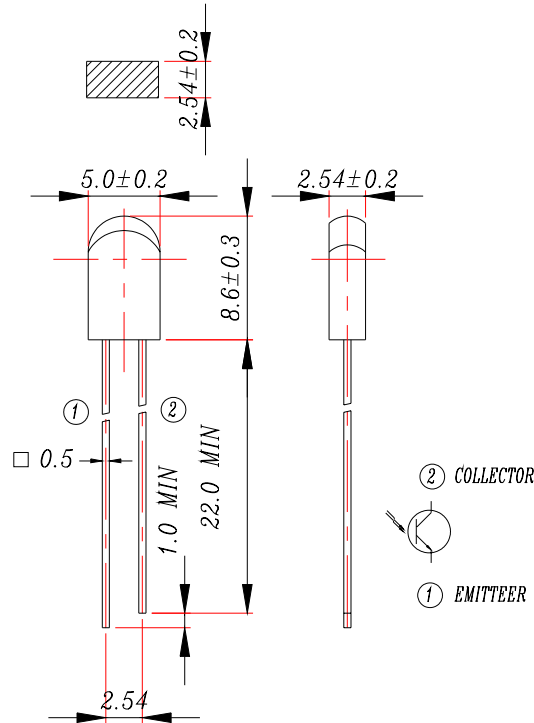
Applications

- Camera
- Infrared applied system

Device Selection Guide

| LED Part No. | Chip | Lens Color |
|--------------|----------|------------|
| | Material | |
| PT | Silicon | Black |

Package Dimensions



- Notes:** 1.All dimensions are in millimeters
 2.Tolerances unless dimensions ± 0.1 mm

Absolute Maximum Ratings (Ta=25°C)

| Parameter | Symbol | Rating | Units |
|--------------------------------------------------------------|-----------|------------|-------|
| Collector-Emitter Voltage | V_{CEO} | 30 | V |
| Emitter-Collector-Voltage | V_{ECO} | 5 | V |
| Collector Current | I_C | 20 | mA |
| Operating Temperature | T_{opr} | -40 ~ +85 | °C |
| Storage Temperature | T_{stg} | -40 ~ +100 | °C |
| Lead Soldering Temperature | T_{sol} | 260 | °C |
| Power Dissipation at (or below) 25°C Free Air Temperature | P_c | 75 | mW |

Notes: *1:Soldering time ≤ 5 seconds.

Electro-Optical Characteristics (Ta=25°C)

| Parameter | Symbol | Condition | Min | Typ | Max | Unit |
|---------------------------------------|-----------------|-----------------------------------------------|-----|----------|-----|---------|
| Collector – Emitter Breakdown Voltage | BV_{CEO} | $I_C=100\ \mu A$ $E_e=0mW/cm^2$ | 30 | --- | --- | V |
| Emitter-Collector Breakdown Voltage | BV_{ECO} | $I_E=100\ \mu A$ $E_e=0mW/cm^2$ | 5 | --- | --- | V |
| Collector-Emitter Saturation Voltage | $V_{CE(sat)}$ | $I_C=2mA$ $E_e=1mW/cm^2$ | --- | --- | 0.4 | V |
| Rise Time | t_r | $V_{CE}=5V$ $I_C=1mA$ $RL=1000\ \Omega$ | --- | 15 | --- | μS |
| Fall Time | t_f | | --- | 15 | --- | |
| Collector Dark Current | I_{CEO} | $E_e=0mW/cm^2$ $V_{CE}=20V$ | --- | --- | 100 | nA |
| On State Collector Current | $I_{C(on)}$ | $E_e=1mW/cm^2$ $V_{CE}=5V$ | 0.7 | 1.2 | --- | mA |
| Wavelength of Peak Sensitivity | λ_p | --- | --- | 980 | --- | nm |
| Rang of Spectral Bandwidth | $\lambda_{0.5}$ | --- | --- | 800-1200 | --- | nm |

Typical Electro-Optical Characteristics Curves

Fig.1 Collector Power Dissipation vs. Ambient Temperature

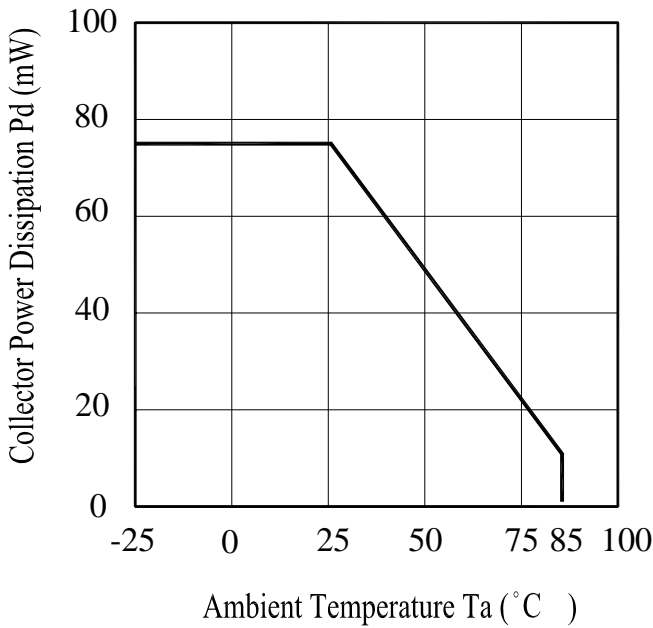


Fig.2 Spectral Sensitivity

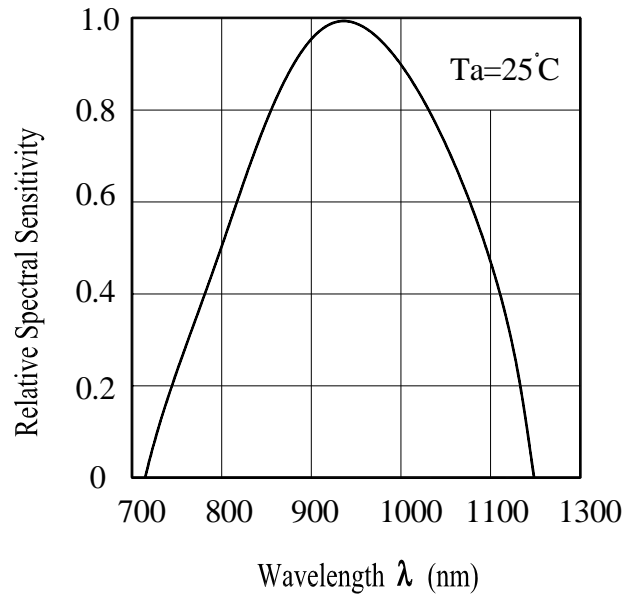


Fig.3 Relative Collector Current vs. Ambient Temperature

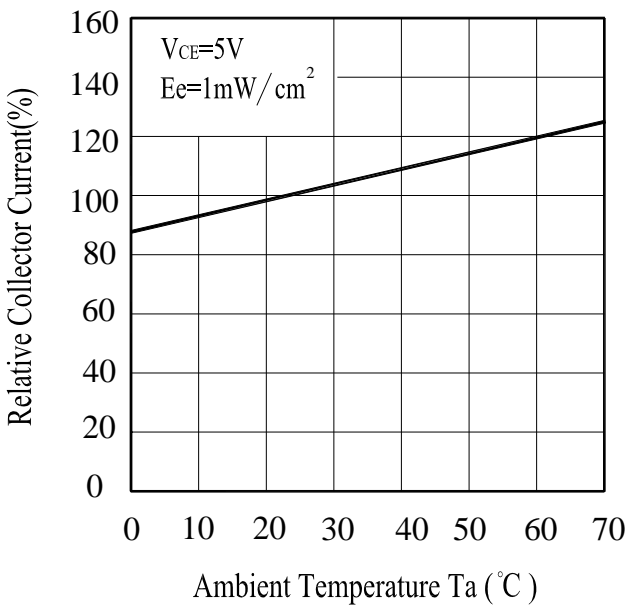
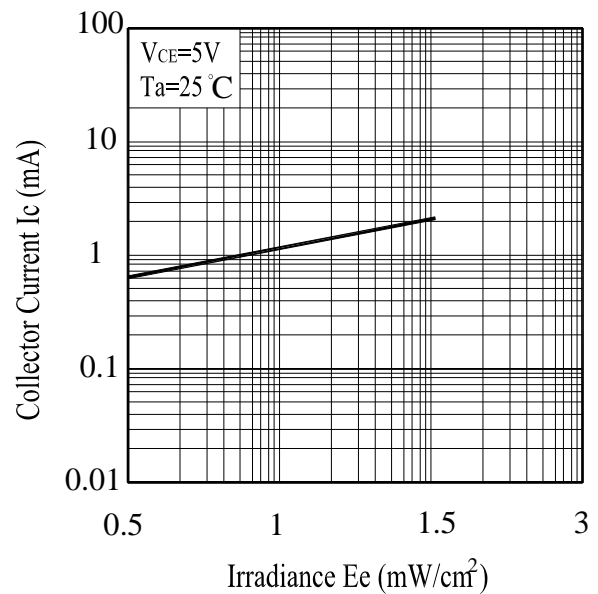


Fig.4 Collector Current vs. Irradiance



Typical Electro-Optical Characteristics Curves

Fig.5 Collector Dark Current vs. Ambient Temperature

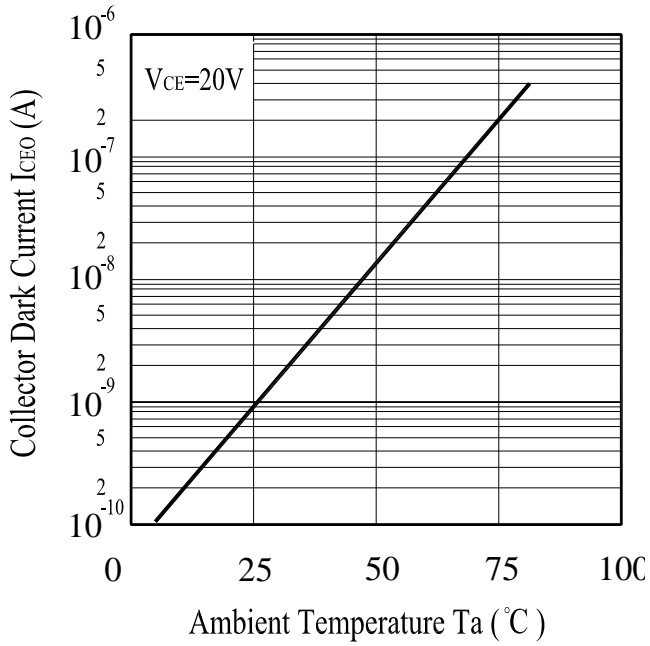
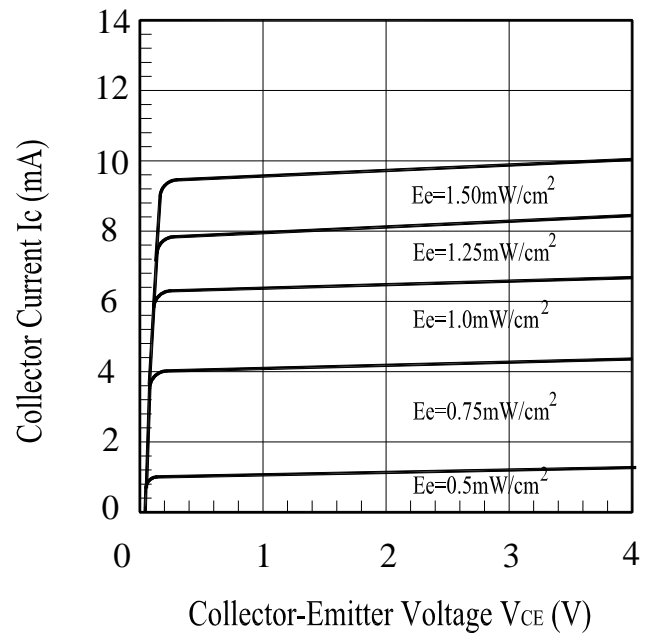


Fig.6 Collector Current vs. Collector-Emitter Voltage



Reliability Test Item And Condition

The reliability of products shall be satisfied with items listed below.

Confidence level : 90%

LTPD : 10%

| NO. | Item | Test Conditions | Test Hours/ Cycles | Sample Sizes | Failure Judgement Criteria | Ac/Re |
|-----|------------------------------------|---------------------------------------------------------------------|-----------------------|-----------------|----------------------------------------------------------------------|-------|
| 1 | Solder Heat | TEMP. : 260°C±5°C | 10secs | 22pcs | $I_{C(ON)} \leq L \times 0.8$ L : Lower Specification Limit | 0/1 |
| 2 | Temperature Cycle | H : +100°C 15mins \updownarrow 5mins L : -40°C 15mins | 50Cycles | 22pcs | | 0/1 |
| 3 | Thermal Shock | H : +100°C 5mins \updownarrow 10secs L : -10°C 5mins | 50Cycles | 22pcs | | 0/1 |
| 4 | High Temperature Storage | TEMP. : +100°C | 1000hrs | 22pcs | | 0/1 |
| 5 | Low Temperature Storage | TEMP. : -40°C | 1000hrs | 22pcs | | 0/1 |
| 6 | DC Operating Life | $V_{CE}=5V$ | 1000hrs | 22pcs | | 0/1 |
| 7 | High Temperature/ High Humidity | 85°C / 85% R.H | 1000hrs | 22pcs | | 0/1 |



Packing Quantity Specification

- 1. 500Pcs/Bags , 6Bags/1Boxes
- 2. 10Boxes/1Carton

Label Form Specification

| | |
|-------------------------------------|----------------------------------------------------------------------------|
| | |
| CPN: P/N: PT534-6B | CPN: Customer's Production Number P/N : Production Number |
| QTY: | QTY: Packing Quantity |
| CAT: HUE: REF: LOT NO: | CAT: Ranks HUE: Peak Wavelength REF: Reference LOT No: Lot Number |

Notes

- 1. Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
- 2. When using this product, please observe the absolute maximum ratings and the instructions for using outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
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